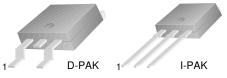


August 2010

KSH200 NPN Epitaxial Silicon Transistor

Features

- · D-PAK for Surface Mount Applications
- · High DC Current Gain
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " I " Suffix)



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	8	V
I _C	Collector Current (DC)	5	Α
I _{CP}	Collector Current (Pulse)	10	Α
I _B	Base Current	1	Α
P _C	Collector Dissipation (T _c = 25°C)	12.5	W
	Collector Dissipation (T _a = 25°C)	1.4	W
T _J	Junction Temperature	150	°C
T _{STG}	T _{STG} Storage Temperature		°C

Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
BV _{CEO} (sus)	* Collector Emitter Sustaining Voltage	$I_C = 100 \text{mA}, I_B = 0$	25		V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 40V, I_{E} = 0$		100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 8V, I_{C} = 0$		100	nA
h _{FE}	* DC Current Gain	$V_{CE} = 1V, I_{C} = 500 \text{mA}$ $V_{CE} = 1V, I_{C} = 2A$ $V_{CE} = 2V, I_{C} = 5A$	70 45 10	180	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = 500$ mA, $I_B = 50$ mA $I_C = 2$ A, $I_B = 200$ mA $I_C = 5$ A, $I_B = 1$ A		0.3 0.75 1.8	V V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C = 5A, I _B = 1A		2.5	V
V _{BE} (on)	* Base-Emitter On Voltage	$V_{CE} = 1V$, $I_C = 2A$		1.6	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 100mA$	65		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 0.1MHz$		80	pF

^{*} Pulse test: PW \leq 300 μ s, Duty Cycle \leq 2% Pulsed

Typical Performance Characteristics

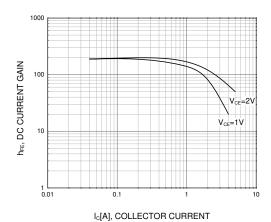


Figure 1. DC current Gain

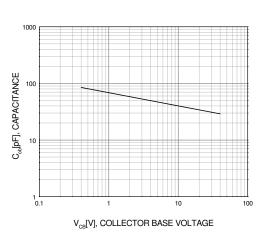


Figure 3. Collector Output Capacitance

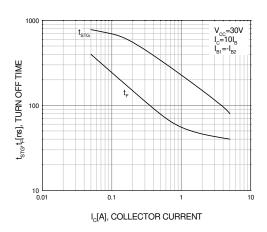


Figure 5. Turn Off Time

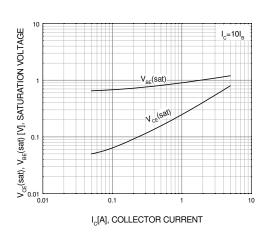


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

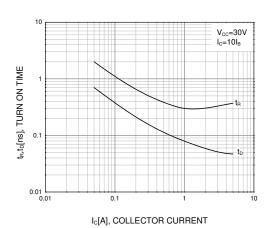


Figure 4. Turn On Time

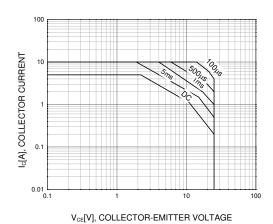


Figure 6. Safe Operating Area

Typical Performance Characteristics (Continued)

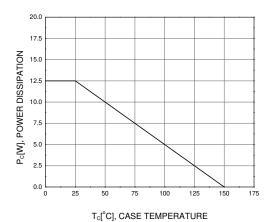
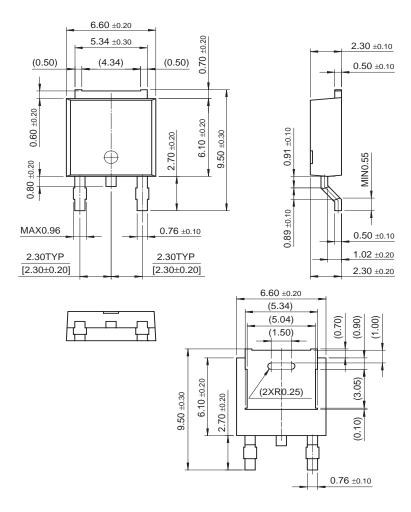


Figure 7. Power Derating

Physical Dimensions

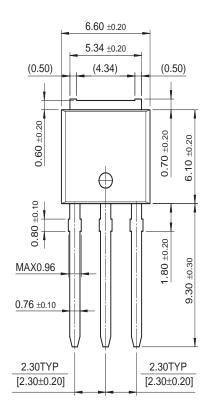
D-PAK

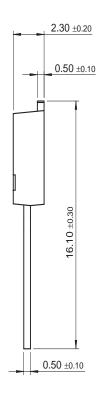


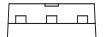
Dimensions in Millimeters

Physical Dimensions (Continued)

I-PAK







Dimensions in Millimeters





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Definition of Terms					
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